



#4

Application Number: 10/082,852
Filing Date: 2-25-02
First Named Inventor: James D. Beasom
Group Art Unit: 2812
Examiner Name: _____
Attorney Docket: INT-0009A

FORM PTO-1449 COMMERCE		U.S. DEPARTMENT OF PATENT AND TRADEMARK OFFICE						
INFORMATION DISCLOSURE STATEMENT BY APPLICANT								
U.S. Patent Documents								
Examiner Initials	Cite No.	U.S. Patent Number	Kind Code	Name of Patentee or Applicant of Cited Document	Date of Publication	Pages, Columns, Lines Where Relevant Passages or Figures Appear		
AR	—	5,652,153	—	Beasom	7-1997	—		
	—	6,225,181	—	Gregory	5-2001	—		
	—	6,258,641	—	Wong et al.	7-2001	—		
	—	5,633,180	—	Bajor	5-1997	—		
MR	—	5,897,362	—	Wallace	4-1999	—		
Examiner Initials	Cite No.	Office	Number	Kind Code	Name of Patentee or Applicant	Date of Publication MM-DD-YY	Location of Relevant Passages/Figures	T
Other Prior Art - Non Patent Literature Documents								
Examiner Initials	Cite No.	Name of Author (All Caps), Title of Article/Item, Date, Page(s), Volume-Issue Number(s), Publisher, City and/or Country Where Published						T
AR	—	Sze, S.M. "Semiconductor Devices, Physics and Technology" John Wiley & Sons, Pg 384						—
Examiner Signature						Date Considered	03/09/04	

**EXAMINER: Initial citation considered. Draw line through citation if no in conformance and not considered. Include copy of this form with next communication to application.

RECEIVED
DEC 31 2002
TECHNICAL CENTER 2800

112/205
D. Beasom
5/16/02

Application Number: _____
Filing Date: _____
First Named Inventor: James D. Beasom
Group Art Unit: _____
Examiner Name: _____
Attorney Docket: INT-0009A

U.S. PTO
10/082852
02/25/02

FORM PTO-1449
COMMERCE

U.S. DEPARTMENT OF
PATENT AND TRADEMARK OFFICE

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

U.S. Patent Documents						
Examiner Initials	Cite No.	U.S. Patent Number	Kind Code	Name of Patentee or Applicant of Cited Document	Date of Publication	Pages, Columns, Lines Where Relevant Passages or Figures Appear
AR	—	5,256,582	—	Mosher, et al	10-26-93	—
	—	4,875,086	—	Malhi, et al	10-17-89	—
	—	6,146,956	—	Pinto, et al	11-14-00	—
	—	5,637,516	—	Muller	06-10-97	—
	—	5,814,538	—	Kim, et al	09-29-98	—
	—	5,892,264	—	Davis, et al	04-06-99	—
AR	—	4,897,698	—	Zorinsky, et al	01-30-90	—

Foreign Patent Documents								
Examiner Initials	Cite No.	Office	Number	Kind Code	Name of Patentee or Applicant	Date of Publication MM-DD-YY	Location of Relevant Passages/Figures	T

Other Prior Art - Non Patent Literature Documents			
Examiner Initials	Cite No	Name of Author (All Caps), Title of Article/Item, Date, Page(s), Volume-Issue Number(s), Publisher, City and/or Country Where Published	T
AR	—	RUPIT PATEL, et al., A 30V Complementary Bipolar Technology on SOI for High Speed Precision Analog Circuits, 1997 IEEE BCTM, pgs. 48-50.	—
AR	—	MC WILSON, et al., Process HJ: A 30 GHz NPN and 20 GHz PNP Complementary Bipolar Process for High Linearity RF Circuits, 1998 IEEE BCTM, pgs. 164-167.	—

Examiner Signature		Date Considered	03/09/04
--------------------	--	-----------------	----------

**EXAMINER: Initial citation considered. Draw line through citation if no in conformance and not considered. Include copy of this form with next communication to application.